

MITSUBISHI IGBT MODULES
CM50TU-24H
 MEDIUM POWER SWITCHING USE
 INSULATED TYPE

CM50TU-24H



- Ic 50A
- VCES 1200V
- Insulated Type
- 6-elements in a pack
- UL Recognized

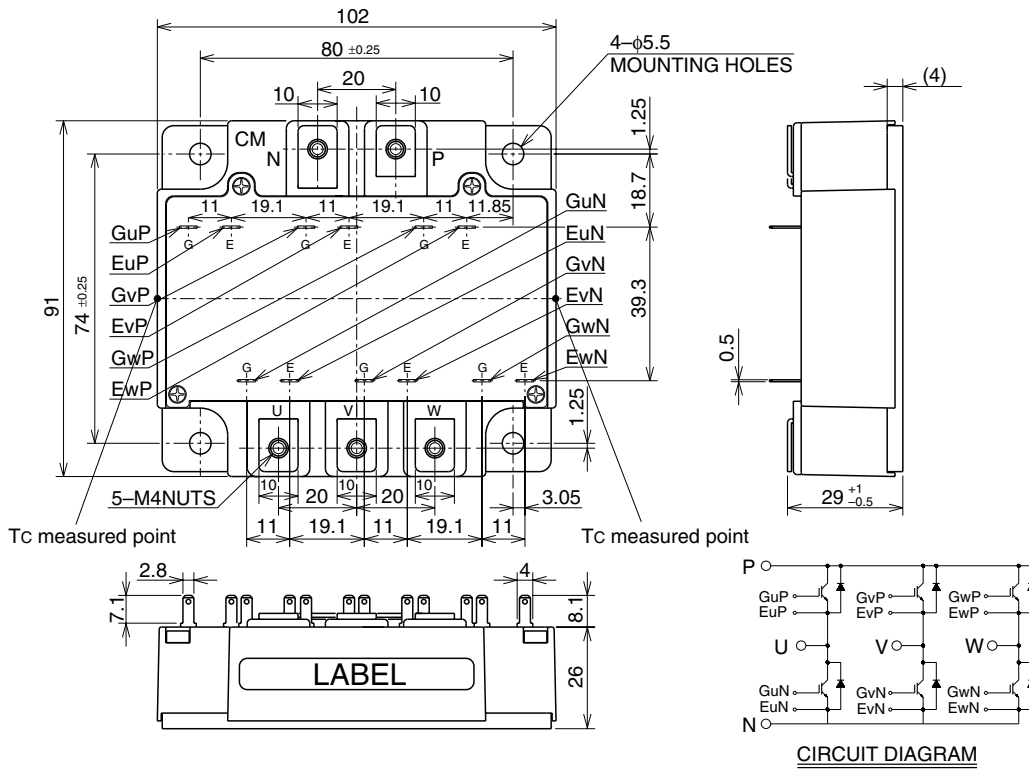
Yellow Card No. E80276
 File No. E80271

APPLICATION

UPS, NC machine, AC-Drive control, Servo, Welders

OUTLINE DRAWING & CIRCUIT DIAGRAM

Dimensions in mm



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MAXIMUM RATINGS (T_j = 25°C, unless otherwise specified)

Symbol	Item	Conditions	Ratings	Unit
V _{CEs}	Collector-emitter voltage	V _{GE} = 0V	1200	V
V _{GES}	Gate-emitter voltage	V _{CE} = 0V	±20	V
I _C	Collector current	T _C = 25°C	50	A
I _{CM}		Pulse (Note 1)	100	A
I _E (Note 2)	Emitter current	T _C = 25°C	50	A
I _{EM} (Note 2)		Pulse (Note 1)	100	A
P _C (Note 3)	Maximum collector dissipation	T _C = 25°C	400	W
T _j	Junction temperature	—	-40 ~ +150	°C
T _{stg}	Storage temperature	—	-40 ~ +125	°C
V _{iso}	Isolation voltage	Charged part to base plate, f = 60Hz, AC 1 minute	2500	V _{rms}
—	Mounting torque	Main terminals M4 screw	1.3 ~ 1.7	N·m
		Mounting M5 screw	2.5 ~ 3.5	N·m
—	Weight	Typical value	570	g

ELECTRICAL CHARACTERISTICS (T_j = 25°C, unless otherwise specified)

Symbol	Item	Test Conditions	Limits			Unit	
			Min	Typ	Max		
I _{CEs}	Collector cutoff current	V _{CE} = V _{CEs} , V _{GE} = 0V	—	—	1	mA	
V _{GE(th)}	Gate-emitter threshold voltage	I _C = 5mA, V _{CE} = 10V	4.5	6	7.5	V	
I _{GES}	Gate-leakage current	±V _{GE} = V _{GES} , V _{CE} = 0V	—	—	0.5	µA	
V _{CE(sat)}	Collector-emitter saturation voltage	I _C = 50A, V _{GE} = 15V (Note 4)	T _j = 25°C	—	2.9	3.7	V
			T _j = 125°C	—	2.85	—	
C _{ies}	Input capacitance	V _{CE} = 10V	—	—	7.5	nF	
C _{oes}	Output capacitance	V _{GE} = 0V	—	—	2.6	nF	
C _{res}	Reverse transfer capacitance	—	—	—	1.5	nF	
Q _G	Total gate charge	V _{CC} = 600V, I _C = 50A, V _{GE} = 15V	—	187	—	nC	
t _{d(on)}	Turn-on delay time	V _{CC} = 600V, I _C = 50A	—	—	80	ns	
t _r	Turn-on rise time	V _{GE} = ±15V	—	—	200	ns	
t _{d(off)}	Turn-off delay time	R _G = 6.3Ω	—	—	150	ns	
t _f	Turn-off fall time	Resistive load	—	—	350	ns	
V _{EC} (Note 2)	Emitter-collector voltage	I _E = 50A, V _{GE} = 0V	—	—	3.2	V	
t _{rr} (Note 2)	Reverse recovery time	I _E = 50A,	—	—	300	ns	
Q _{rr} (Note 2)	Reverse recovery charge	die / dt = -100A / µs	—	0.28	—	µC	
R _{th(j-c)Q}	Thermal resistance (Note 5)	Junction to case, IGBT part (Per 1/6 module)	—	—	0.31	K/W	
R _{th(j-c)R}		Junction to case, FWDi part (Per 1/6 module)	—	—	0.7	K/W	
R _{th(c-f)}	Contact thermal resistance	Case to heat sink, conductive grease applied (Per 1/6 module) (Note 6)	—	0.11	—	K/W	

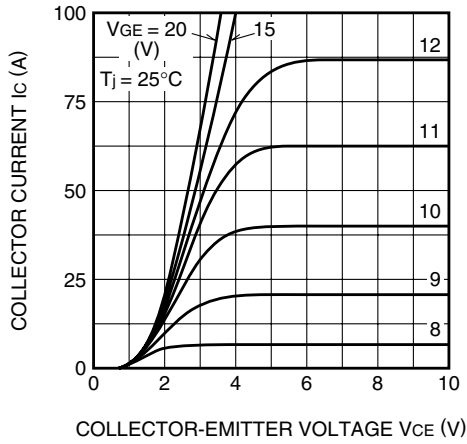
- Note 1. Pulse width and repetition rate should be such that the device junction temperature (T_j) does not exceed T_{jmax} rating.
 2. I_E, V_{EC}, t_{rr}, Q_{rr} & die/dt represent characteristics of the anti-parallel, emitter-collector free-wheel diode.
 3. Junction temperature (T_j) should not increase beyond 150°C.
 4. Pulse width and repetition rate should be such as to cause negligible temperature rise.
 5. Case temperature (T_C) measured point is shown in page OUTLINE DRAWING.
 6. Typical value is measured by using thermally conductive grease of λ = 0.9[W/(m · K)].

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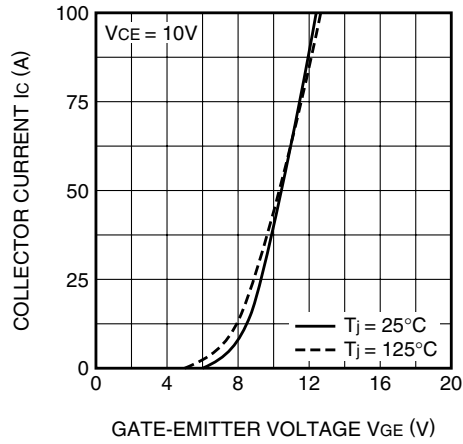
MEDIUM POWER SWITCHING USE
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PERFORMANCE CURVES

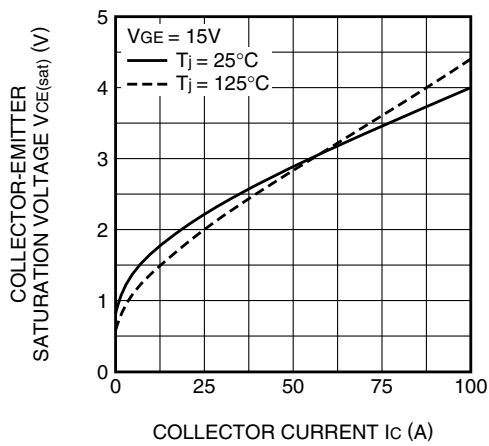
OUTPUT CHARACTERISTICS (TYPICAL)



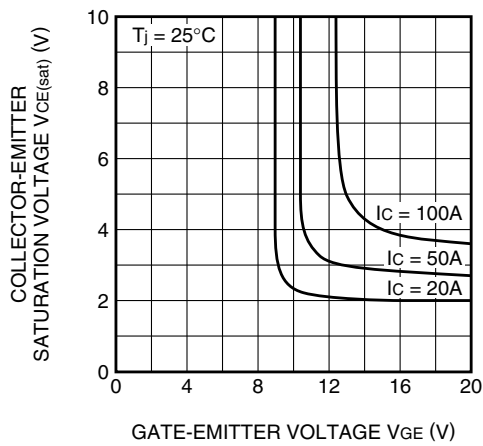
TRANSFER CHARACTERISTICS (TYPICAL)



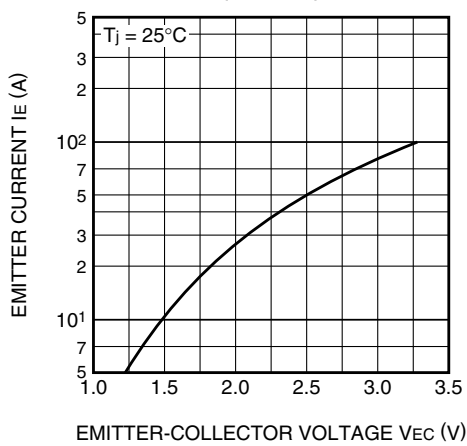
COLLECTOR-EMITTER SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)



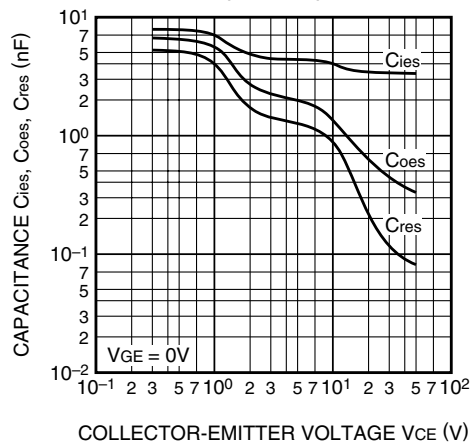
COLLECTOR-EMITTER SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)



FREE-WHEEL DIODE FORWARD CHARACTERISTICS (TYPICAL)



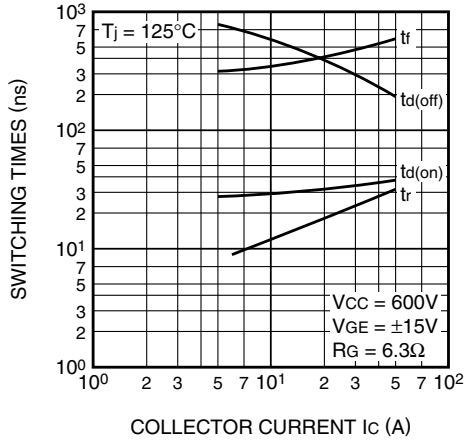
CAPACITANCE CHARACTERISTICS (TYPICAL)



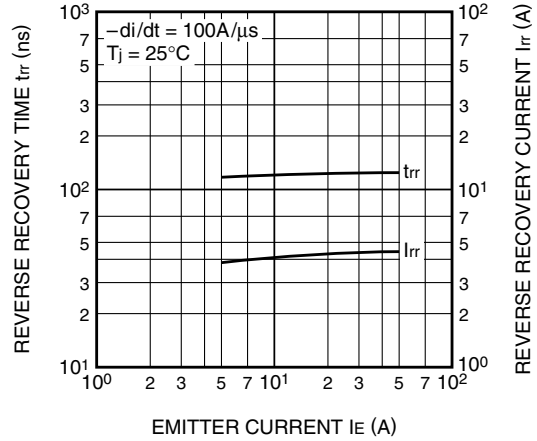
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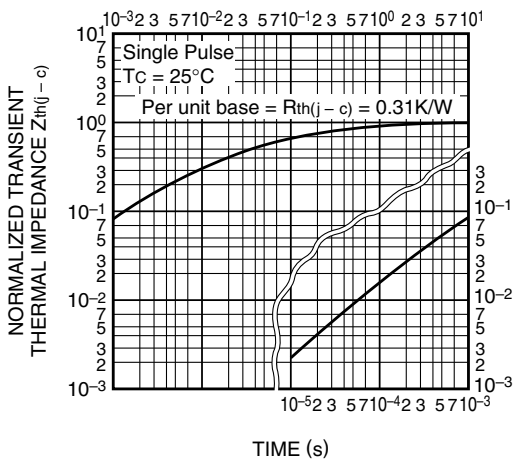
**HALF-BRIDGE
SWITCHING TIME CHARACTERISTICS
(TYPICAL)**



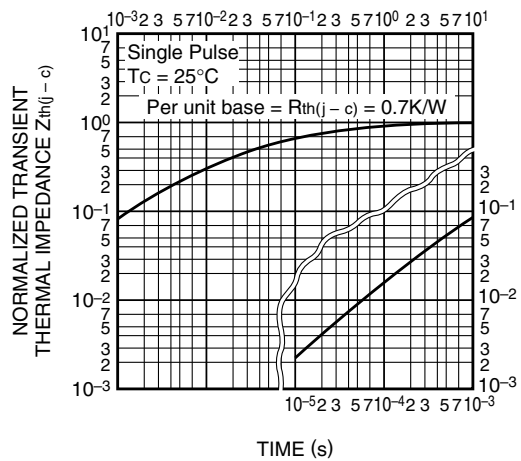
**REVERSE RECOVERY CHARACTERISTICS
OF FREE-WHEEL DIODE
(TYPICAL)**



**TRANSIENT THERMAL
IMPEDANCE CHARACTERISTICS
(IGBT part)**



**TRANSIENT THERMAL
IMPEDANCE CHARACTERISTICS
(FWDi part)**



**GATE CHARGE CHARACTERISTICS
(TYPICAL)**

